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Substitute for form 1449A/PTO 34	Complete if Known
	Application Number
	Filing Date 03/30/2004
STATEMENT BY APPLICANT	First Named Inventor Rupich Martin W.

Application Number	
	03/30/2004
First Named Inventor	Rupich Martin W.
ArtiUnit*	
Examiner Name	
Attorney Docket Number	2802:169US1FAMSC-662

Examiner	Cite	Document Number	U. S. PATENT Publication Date	Name of Patentee or	Pages, Columns, Lines, Where
nitials*	No.1	Number-Kind Code ^{2 (7 known)}	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
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	FOREIGN PATENT DOCUMENTS					
Examiner	Cite	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
Initials*	No.'	Country Code ³ Number ⁴ Kind Code ⁵ (if known)				1,
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Substitute for form 1449B/PTO	200	Complete if Known
	Application Number	
information disclosure	Filing Date	03/30/2004
STATEMENT BY APPLICANT	First Named Inventor	Rupich, Martin W:
	Art Unit	
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		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
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